

Support Information

**Three-dimensional Ni_{0.85}Se@ZnSe nanostructures on carbon cloth for
flexible asymmetric battery-type supercapacitor**

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Contents:

1. Electrochemical Measurements
2. Material characterization
3. Supplementary figures S1-S9
4. Supplementary tables S1-S5
5. Supplementary References

1. Electrochemical performance test

After washing, the electrode materials obtained by electrodeposition were put into a vacuum drying oven and dried for 12 h at 60 °C. The electrolyte solution required for all electrochemical tests was 4 M KOH. The reference electrode, counter electrode and working electrode of the test system were Mercury oxide (Hg/HgO), platinum sheet electrode and electrodeposited active material electrode respectively. The voltage window range of cyclic voltammetry curve (CV) is set as 0-0.6V, and the voltage window range of constant current charge-discharge curve (GCD) is set as 0-0.5V (mono is: 0-0.45), the Energy Quest curve (EIS) was tested at an open circuit potential in the frequency range of 0.01Hz-100khz, and electrochemical performance was tested at the electrochemical workstation (CHI660E, Shanghai Chenhua). In the two-electrode test system, Ni_{0.85}Se@ZnSe was used as the positive electrode and activated carbon (AC) as the negative electrode.

The discharge time (Δt) of the GCD curve is proportional to the electrochemical capacity (C_m , F g⁻¹) of the electrode material. Eq (S1) as follows:

$$C_m = \frac{I \times \Delta t}{m \times \Delta v} \quad (S1)$$

where I is the discharge current density (A g⁻¹); m represents the mass of active materials grown on CC for three-electrode configurations (g); Δt is the discharge time (s); and ΔV is the potential window (V).

The energy density (E, Wh kg⁻¹) and power density (P, W kg⁻¹) of the ASCs are were investigated by eqs (S2) and (S3), respectively, as follows:

$$E = \frac{C_m \times \Delta V^2}{3.6 \times 2} \quad (S2)$$

$$P = \frac{3600E}{\Delta t} \quad (S3)$$

2. Material characterization

The phase characterization of the sample Ni_{0.85}Se@ZnSe nanospheres was

performed by X-Ray powder diffractometer (XRD, Japanese, Rigaku D/Max-3c) Cu Ka ($\lambda=1.5418 \text{ \AA}$), the test voltage was 40 kV; The morphology, energy spectrum (EDS) and elemental analysis (mapping) of the sample were characterized by emission scanning electron microscope (FE-SEM, Hitachi S-4800, Japan); X-ray electron spectroscopy (XPS, UK AXIS SUPRA (Kratos)) was used. The composition and valence state of the sample elements were analyzed; the transmission electron microscope (TEM, FEI Tecnai G2F20, USA) characterized the microstructure of the sample.

3. Supplementary figures



Figure S1. The photographs of the $\text{Ni}_{0.85}\text{Se}@\text{ZnSe}$ CC electrode under folded and twisted conditions

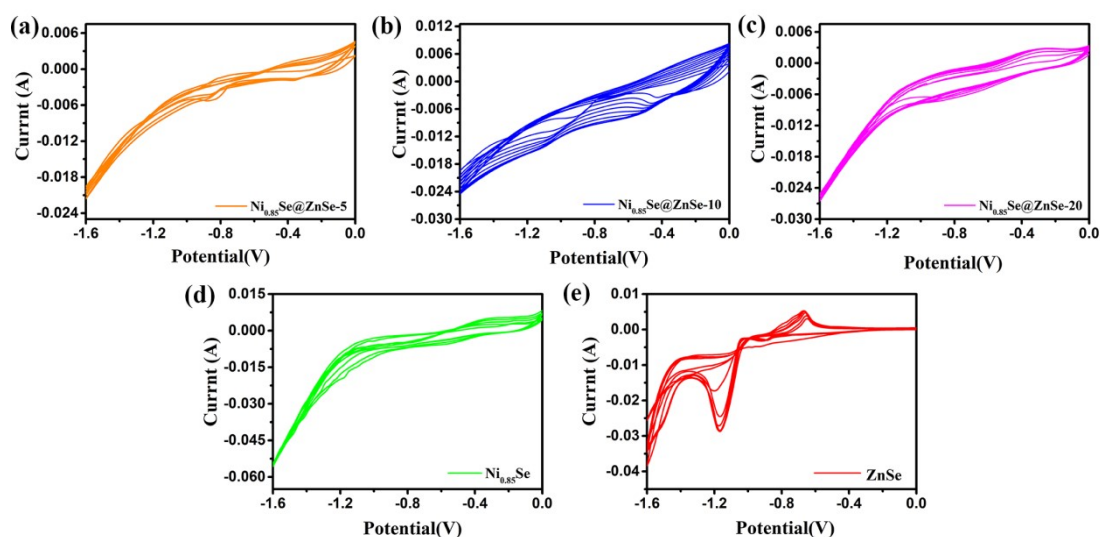


Figure S2. CV curves during electrodeposition process

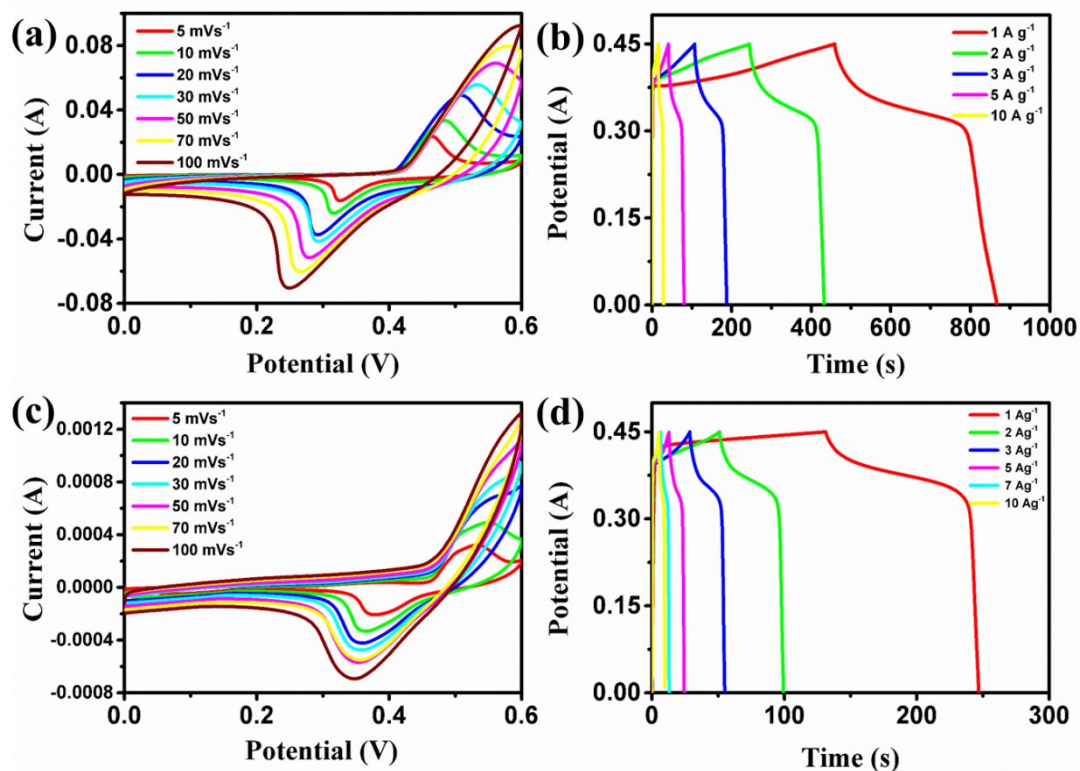


Figure S3. (a, c) CV curves of the $\text{Ni}_{0.85}\text{Se}$, ZnSe at different scan rates, (b, d) GCD curves of the $\text{Ni}_{0.85}\text{Se}$, ZnSe at different electric current density.

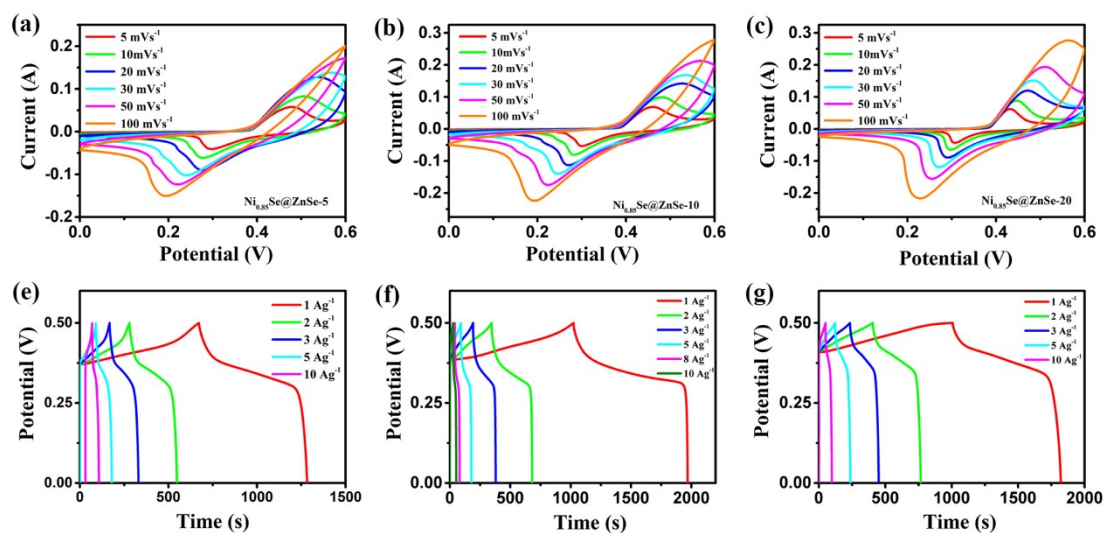


Figure S4. (a, b, c) CV curves of the $\text{Ni}_{0.85}\text{Se@ZnSe-5}$, $\text{Ni}_{0.85}\text{Se@ZnSe-10}$, $\text{Ni}_{0.85}\text{Se@ZnSe-20}$ at different scan rates, (d, e, f) GCD curves of the $\text{Ni}_{0.85}\text{Se@ZnSe-5}$, $\text{Ni}_{0.85}\text{Se@ZnSe-10}$, $\text{Ni}_{0.85}\text{Se@ZnSe-20}$ at different electric current density.

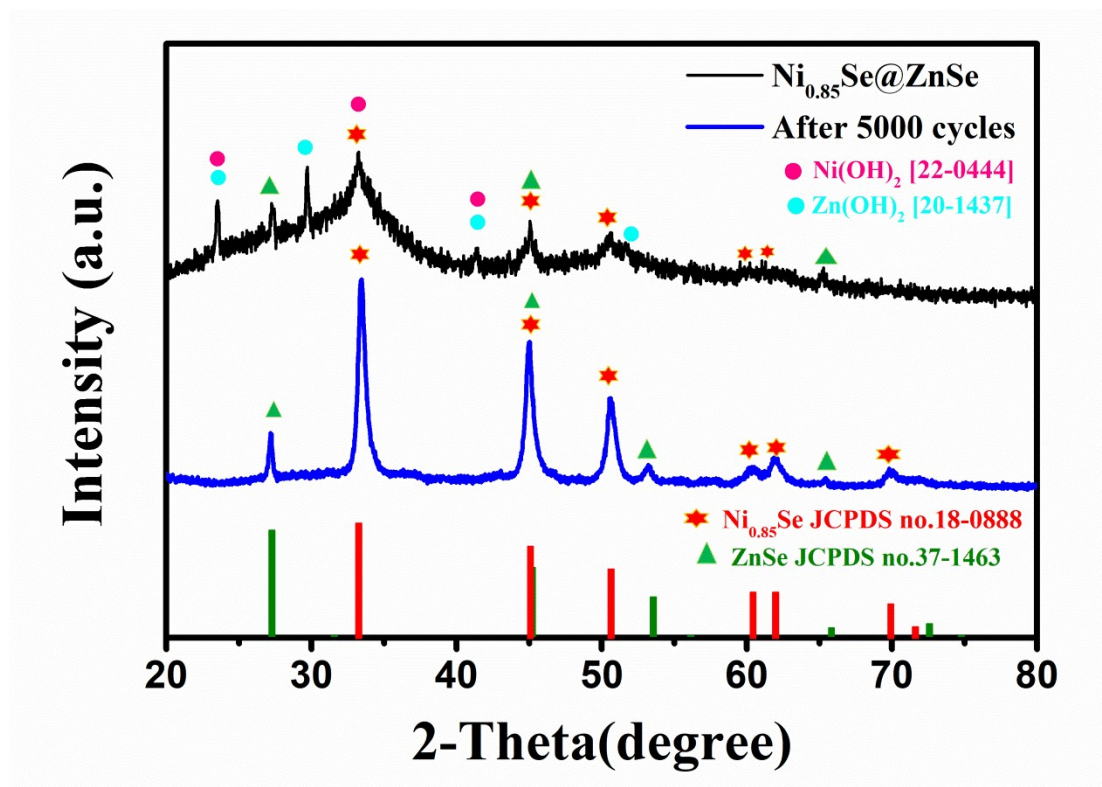


Figure S5. XRD patterns of the $\text{Ni}_{0.85}\text{Se@ZnSe-10}$ (blue line) and $\text{Ni}_{0.85}\text{Se@ZnSe-10}$ electrode after cycling tests (black line)

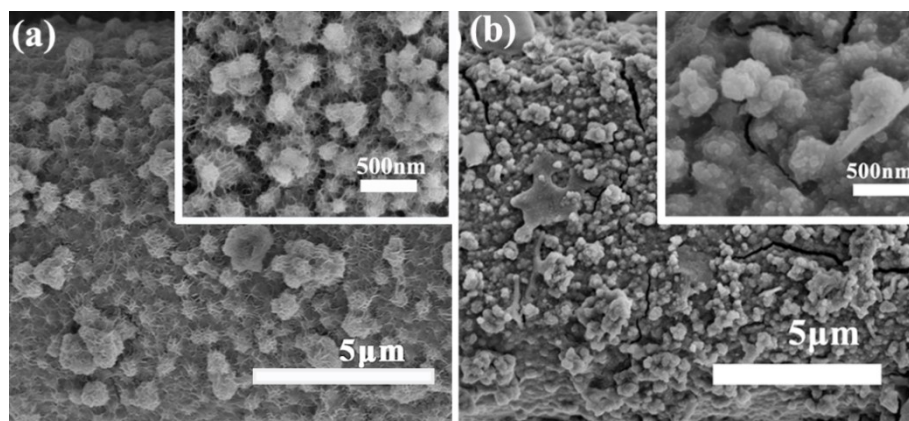


Figure S6. (a) SEM images of $\text{Ni}_{0.85}\text{Se@ZnSe-10}$, (b) SEM images of $\text{Ni}_{0.85}\text{Se@ZnSe-10}$ cycling at 10 A g^{-1} for 5000 times

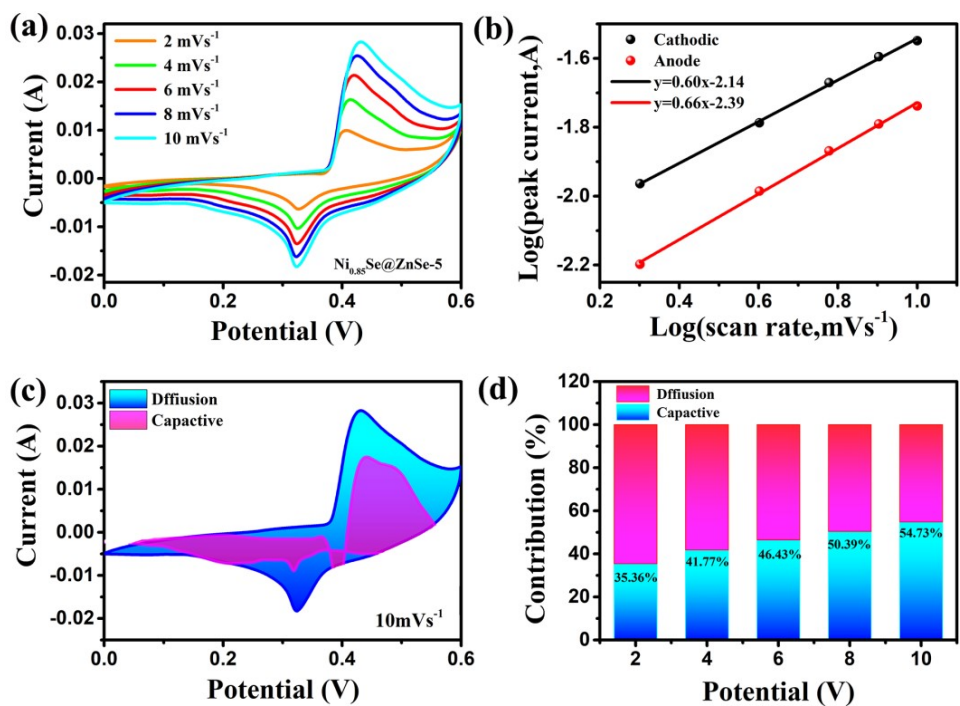


Figure S7. Quantitative capacitive analysis of energy storage behavior: (a) the CV curves of $\text{Ni}_{0.85}\text{Se}@Z\text{nSe-5}$, (b) the curves of $\log(i)$ and $\log(V)$, (c) the capacitive contribution for $\text{Ni}_{0.85}\text{Se}@Z\text{nSe-5}$ and diffusion contribution (blue) at a scan of 10 mV s^{-1} , (d) comparison of charge storage for $\text{Ni}_{0.85}\text{Se}@Z\text{nSe-5}$ electrodes at different scan rates.

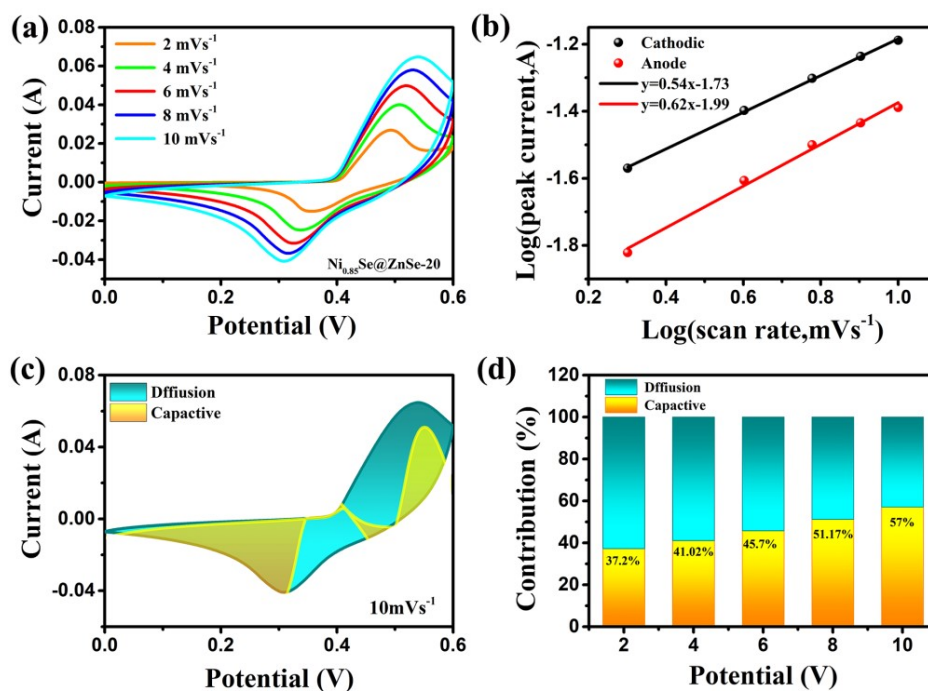


Figure S8. Quantitative capacitive analysis of energy storage behavior: (a) the CV curves of $\text{Ni}_{0.85}\text{Se}@\text{ZnSe}-20$, (b) the curves of $\log(i)$ and $\log(V)$, (c) the capacitive contribution for $\text{Ni}_{0.85}\text{Se}@\text{ZnSe}-20$ and diffusion contribution (blue) at a scan of 10 mV s^{-1} , (d) comparison of charge storage for $\text{Ni}_{0.85}\text{Se}@\text{ZnSe}-20$ electrodes at different scan rates.

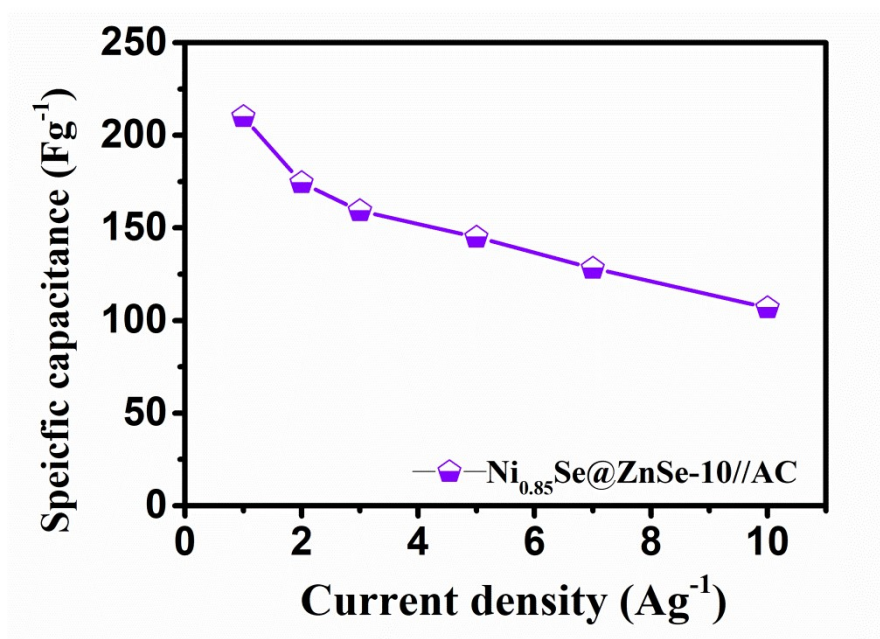


Figure S9. The capacity ratio of $\text{Ni}_{0.85}\text{Se}@\text{ZnSe}-10//\text{AC}$ ACS

4. Supplementary tables S1-S4

Table S1. Fitted parameters of the Nyquist plots in Fig. 5f using equivalent circuits.

samples	R_s (Ω)	R_{ct} (Ω)
ZnSe	1.387	1.98
Ni _{0.85} Se	1.174	1.46
Ni _{0.85} Se@ZnSe-5	0.69	1.38
Ni _{0.85} Se@ZnSe-10	0.47	1.14
Ni _{0.85} Se@ZnSe-20	0.64	1.26

Table S2. The Ni_{0.85}Se@ZnSe-10 of elemental composition of Smart quant results by the EDS.

<i>Element</i>	<i>Wt%</i>	<i>At%</i>
<i>SeL</i>	58.14	52.83
<i>NiK</i>	24.06	29.45
<i>ZnK</i>	16.13	17.72

Table S3. The specific capacity (F g⁻¹) at different current densities in Figure 5e.

	1 A g ⁻¹	2 A g ⁻¹	3 A g ⁻¹	5 A g ⁻¹	10 A g ⁻¹
ZnSe	258	216.5	187	138.9	118.5
Ni_{0.85}Se	917	832.5	538.7	467	405
Ni_{0.85}Se@ZnSe-5	1228	1077	992	900	766
Ni_{0.85}Se@ZnSe-10	1927	1629,	1448,	1310	1058
Ni_{0.85}Se@ZnSe-20	1674	1448	1296	1085	912

Table S4. Comparison of the capacity performance of as-prepared Ni_{0.85}Se@ZnSe and other metallic selenides electrode materials reported previously.

Electrode material	Special capacity	Morphology	Current density	Ref
Ni _{0.85} Se@ZnSe	nanosturcures	1927 F g ⁻¹	1A g ⁻¹	This work

Ni _{0.85} Se@MoSe ₂	nanostructures	774 F g ⁻¹	1 A g ⁻¹	Manuscript 34
NiFe ₂ Se ₄	particle-like	372.2 mA h g ⁻¹	1 A g ⁻¹	Manuscript 29
	microstructure	(1339.92 F g ⁻¹)		
NiCoSe ₂	nanostructure	2185 F g ⁻¹	1 A g ⁻¹	Manuscript 22
NiMoO ₄	heterostructured	1061 F g ⁻¹	2 A g ⁻¹	Manuscript 36
Cu _{0.5} Co _{0.5} Se ₂	nanosheets	1695 F g ⁻¹	1 A g ⁻¹	1
Mn-Co-Se	urchin-like	1656 F g ⁻¹	1 A g ⁻¹	2
CoNi ₂ Se ₄	flake-like	1505 F g ⁻¹	1 A g ⁻¹	3
NiCoSe ₂	ellipsoid	1408 F g ⁻¹	1 A g ⁻¹	4
	structure			
Ni _{0.9} Co _{1.92} Se ₄	coral-like	510.55 C g ⁻¹	2 mA	6
		(1021.1 F g ⁻¹)	cm ⁻²	
(Ni,Co)Se ₂	cactus-like	972 F g ⁻¹	2 A g ⁻¹	7
	structure			
Co-Cd-Se	nanorods	192 mA h g ⁻¹	1 A g ⁻¹	5
		(1382 F g ⁻¹)		
CoFe ₂ Se ₄ -CoNiSe ₂	composite	183.4 mA h g ⁻¹	1 A g ⁻¹	8
		(1320.5 F g ⁻¹)		
NiFe ₂ Se ₄	particle-like	126.9 F g ⁻¹	1 A g ⁻¹	9
	microstructure			
Ni-Co-Se	hollow	584 C g ⁻¹	1 A g ⁻¹	10
	nanoparticles	(1168 F g ⁻¹)		
Ni _{0.6} Co _{0.4} Se ₂	reed mat-like	1580 F g ⁻¹	1 A g ⁻¹	11
	sheets			
NiCo ₂ O ₄ @Ni _{0.85} Se	core-shell	1454 F g ⁻¹	1 A g ⁻¹	13
	architecture			

Table S5 Comparison of the performance of Ni_{0.85}Se@ZnSe //AC with those of reported HSC devices based on metallic selenides.

Supercapacitors	Specific energy (Wh Kg ⁻¹)	Specific power W Kg ⁻¹	Ref
Ni _{0.85} Se@ZnSe //AC ASC	74.67 Wh kg ⁻¹	800 W kg ⁻¹	This work
NFSe-20//AC	45.6 Wh kg ⁻¹	800 W kg ⁻¹	manuscript 29
Ni _{0.85} Se@MoSe ₂ //GNS	25.2 Wh kg ⁻¹	420 W kg ⁻¹	Manuscript 34
ZNSe@NCS@NF//AC@NF	52.37Wh kg ⁻¹	800 W kg ⁻¹	Manuscript 24
NCS-5//AC	41.8Wh kg ⁻¹	800W kg ⁻¹	Manuscript 22
NiMoO ₄ //APC	31.8Wh kg ⁻¹	786.5W kg ⁻¹	Manuscript 36
Cu _{0.5} Co _{0.5} Se ₂ //Ti ₃ C ₂	84.17 Wh kg ⁻¹	604 W kg ⁻¹	1
Mn-Co-Se//AC	55.1 Wh kg ⁻¹	880 W kg ⁻¹	2
Ni _{0.9} Co _{1.92} Se ₄ //AC	26.29 Wh kg ⁻¹	265 W kg ⁻¹	6
(Ni ₃ Co)Se ₂ /NiCo-LDH//PC	39 Wh kg ⁻¹	1650 W kg ⁻¹	7
Co-Cd-Se// /Fe alkaline	57.6Wh Kg ⁻¹	10.9 kW kg ⁻¹	5
CFS–CNS//CFS–CN	80.2 W h kg ⁻¹	1000 W kg ⁻¹	8
NiFe ₂ Se ₄ //AC	45.6 W h kg ⁻¹	800 W kg ⁻¹	9
Ni-Co-Se//RGO	41.8 W h kg ⁻¹	750 W kg ⁻¹	10
Ni _{0.6} Co _{0.4} Se ₂ //AC	44.1 W h kg ⁻¹	691.3 W kg ⁻¹	11
(Ni,Cu)Se ₂ //AC	44.46 Wh kg ⁻¹	797.9 W kg ⁻¹	12
NiCo ₂ O ₄ @Ni _{0.85} Se //AC	29.3 Wh kg ⁻¹	799 W kg ⁻¹	13

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